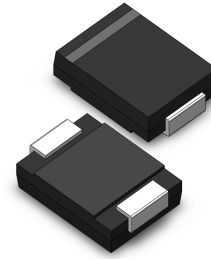


SURFACE MOUNT SCHOTTKY BARRIER DIODES

VOLTAGE RANGE: 20 - 100V
CURRENT: 3.0 A

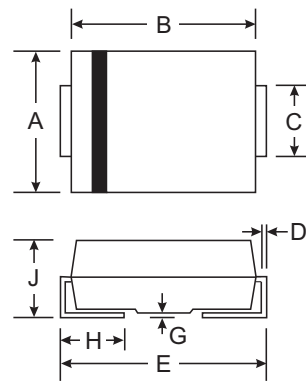


Features

- For Surface Mounted Applications
- High Temperature Metallurgically Bonded Contacts
- High Reliability
- High Current Capability and Low VF
- Submersible Temperature of 265°C for 10 Seconds in Solder Bath

Mechanical Data

- Case: SMC/DO-214AB, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.21 grams (approx.)



SMC/DO-214AB		
Dim	Min	Max
A	5.59	6.22
B	6.60	7.11
C	2.75	3.18
D	0.15	0.31
E	7.75	8.13
G	0.10	0.20
H	0.76	1.52
J	2.00	2.62
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SS32C	SS33C	SS34C	SS35C	SS36C	SS38C	SS310C	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	V
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	V
Maximum average forward rectified current at TL(see fig.1)	I _(AV)	3.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	100.0							A
Maximum instantaneous forward voltage at 3.0A	V _F	0.50		0.70		0.85		V	
Maximum DC reverse current at rated DC blocking voltage <small>T_A=25°C</small> <small>T_A=100°C</small>	I _R	0.5							mA
		20		10					
Typical junction capacitance (NOTE 1)	C _J	500		300				pF	
Typical thermal resistance (NOTE 2)	R _{θJA}	55.0							°C/W
Operating junction temperature range	T _J	-65 to +125			-65 to +150			°C	
Storage temperature range	T _{STG}	-65 to +150							°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

